TOSHIBA Transistor Silicon NPN Epitaxial Type

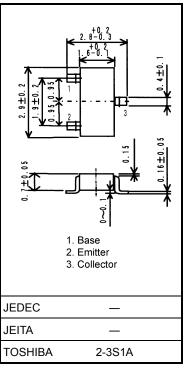
2SC5703

High-Speed Switching Applications DC-DC Converter Applications Strobe Applications

- High DC current gain: $h_{FE} = 400$ to $1000 (I_C = 0.5 \text{ A})$
- Low collector-emitter saturation voltage: V_{CE} (sat) = 0.12 V (max)
- High-speed switching: $t_f = 55 \text{ ns} (typ.)$

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	100	V	
Collector-emitter voltage		V _{CEX}	80	V	
Collector-emitter voltage		V _{CEO}	50	V	
Emitter-base voltage		V _{EBO}	7	V	
Collector current	DC	Ι _C	4	A	
	Pulse	I _{CP}	7		
Base current		Ι _Β	400	mA	
Collector power dissipation	DC	P _C	800	mW	
	t = 10 s	(Note)	1250		
Junction temperature		Тј	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.01 g (typ.)

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current		I _{CBO}	$V_{CB} = 100 \text{ V}, \ I_E = 0$			100	nA	
Emitter cut-off current		I _{EBO}	$V_{EB}=7~V,~I_C=0$	_	_	100	nA	
Collector-emitter breakdown voltage		V (BR) CEO	$I_C = 10 \text{ mA}, I_B = 0$	50	_	_	V	
DC current gain		h _{FE} (1)	$V_{CE} = 2 V, I_C = 0.5 A$	400	_	1000		
		h _{FE} (2)	$V_{CE} = 2 V, I_C = 1.6 A$	200	_	_		
Collector-emitter saturation voltage		V _{CE (sat)}	$I_{C} = 1.6 \text{ A}, I_{B} = 32 \text{ mA}$	_	_	0.12	V	
Base-emitter saturation voltage		V _{BE (sat)}	$I_{C} = 1.6 \text{ A}, I_{B} = 32 \text{ mA}$	_	_	1.10	V	
Collector output capacitance		C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	26	_	pF	
Switching time	Rise time	tr	See Figure 1 circuit diagram.	_	45	_		
	Storage time	t _{stg}	$V_{CC}\simeq 30~V,~R_L=19~\Omega$		700	_	ns	
	Fall time	t _f	$I_{B1} = -I_{B2} = 53.3 \text{ mA}$	_	55	_		

Unit: mm

Note: Mounted on an FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm^2)

Marking

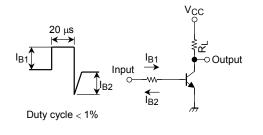
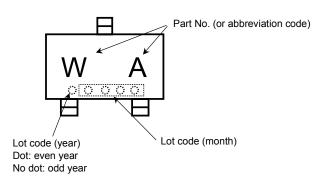
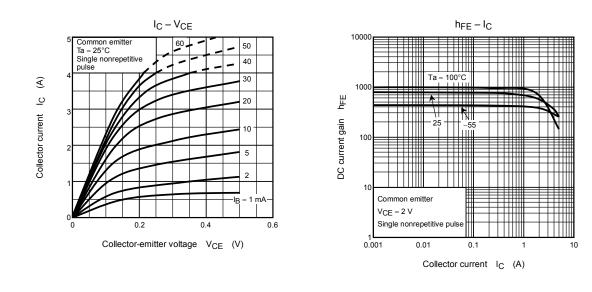


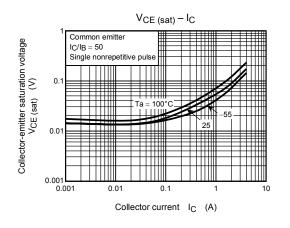
Figure 1 Switching Time Test Circuit & Timing Chart

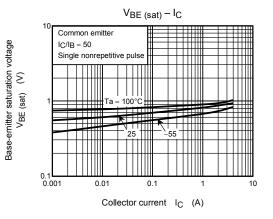


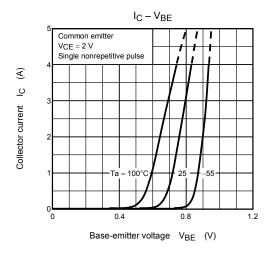
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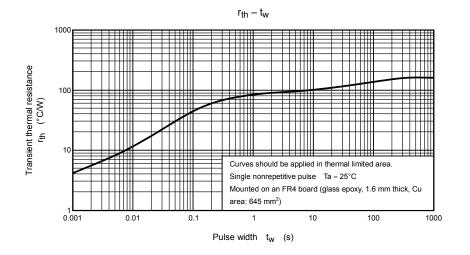
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Safe Operating Area ¹⁰ IC max (pulsed) ♦ 10 ms ♦ 1 ms ♦ 100 μs ♦ 10 us♦ IC max (continuous) 100 ms (E <u>ں</u> 10 s • * DC operation Collector current (Ta = 25°C) 1.1.1111 ◆: Single nonrepetitive pulse Ta = 25°C Note that the curves for 100 ms*, 10 s* and DC operation* will be different when the devices aren't mounted on an FR4 board (glass epoxy, 1,6 mm thick, Cu area: 645 mm³). These characteristic curves must be derated linearly with increase in temperature. 0.1 0.01 0.1 1 10 100 Collector-emitter voltage V_{CE} (V)

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